

RJE0625JPV

P Channel Thermal FET Series Power Switching

R07DS1529EJ0100 Rev.1.00 Mar 30, 2023

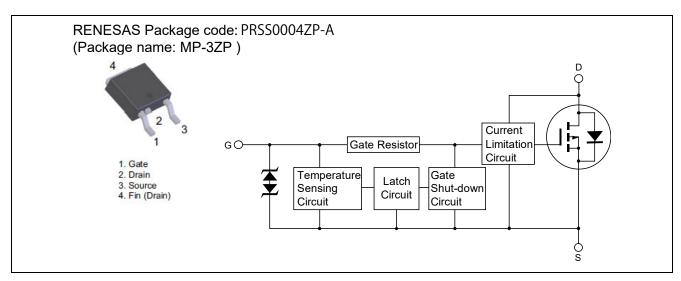
Description

This FET has the over temperature shut-down capability sensing to the junction temperature. This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc..

Features

- Logic level operation (-6 V Gate drive).
- Built-in the over temperature shut-down circuit.
- High endurance capability against to the short circuit.
- Latch type shut down operation (need 0 voltage recovery).
- Built-in the current limitation circuit.
- AEC-Q101 Rev-E Compliant

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	-60	V
Gate to source voltage	V_{GSS}	-16	V
Gate to source voltage	V _{GSS}	2.5	V
Drain current	I _D Note3	-17	Α
Body-drain diode reverse drain current	I _{DR}	-17	A
Avalanche current	I _{AP} Note 2	-8	A
Avalanche energy	E _{AR} Note 2	274	mJ
Channel dissipation	Pch Note 1	50	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	<i>–</i> 55∼+150	°C

Notes: 1. Value at Tc = 25°C

- 2. Tch = 25°C, Rg \geq 50 Ω
- 3. It provides by the current limitation lower bound value.

Typical Operation Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	ViH	-3.5	_	_	V	
	VIL		_	-1.2	V	
Input current	I _{IH1}		_	-100	μΑ	Vi = -8 V, V _{DS} = 0
(Gate non shut down)	I _{IH2}	_	_	-50	μΑ	$Vi = -3.5 V, V_{DS} = 0$
	I _{IL}	_	_	-1	μΑ	Vi = -1.2 V, V _{DS} = 0
Input current	I _{IH(sd)1}	_	-0.8	_	mA	$Vi = -8 V, V_{DS} = 0$
(Gate shut down)	I _{IH(sd)2}	_	-0.35	_	mA	Vi = -3.5 V, V _{DS} = 0
Shut down temperature	Tsd	_	175	_	°C	Channel temperature
						$(dv/dt \ V_{GS} \geq 500 \ V/ms)$
Gate operation voltage	Vop	-3.5	_	-12	V	
Drain current	I _{D limt}	-17	_	_	Α	$V_{GS} = -12 \text{ V}, V_{DS} = -10 \text{ V}^{\text{Note 4}}$
(Current limitation value)						

Notes; 4. Pulse test

Electrical Characteristics

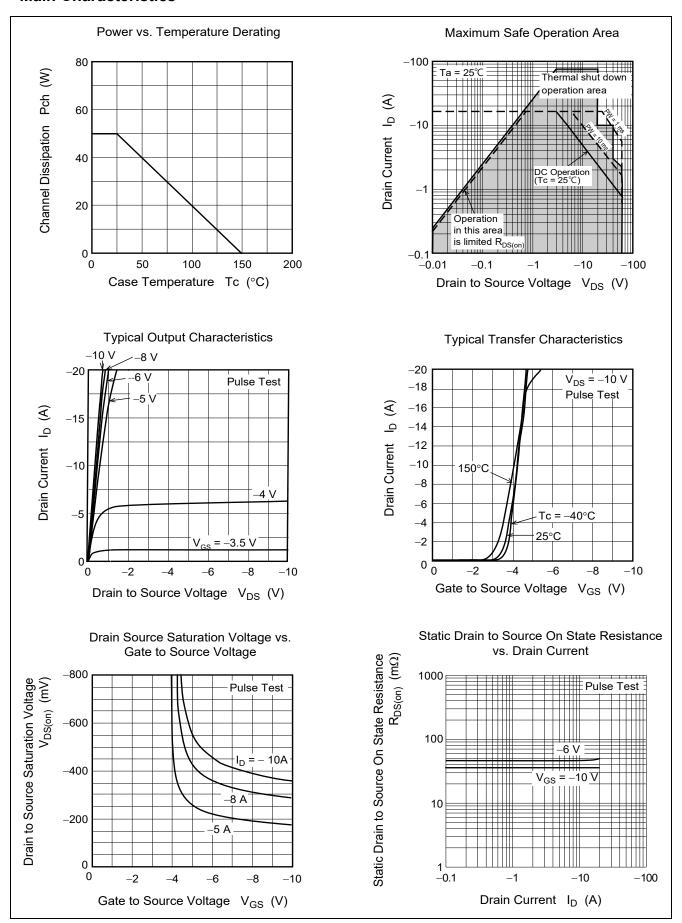
 $(Ta = 25^{\circ}C)$

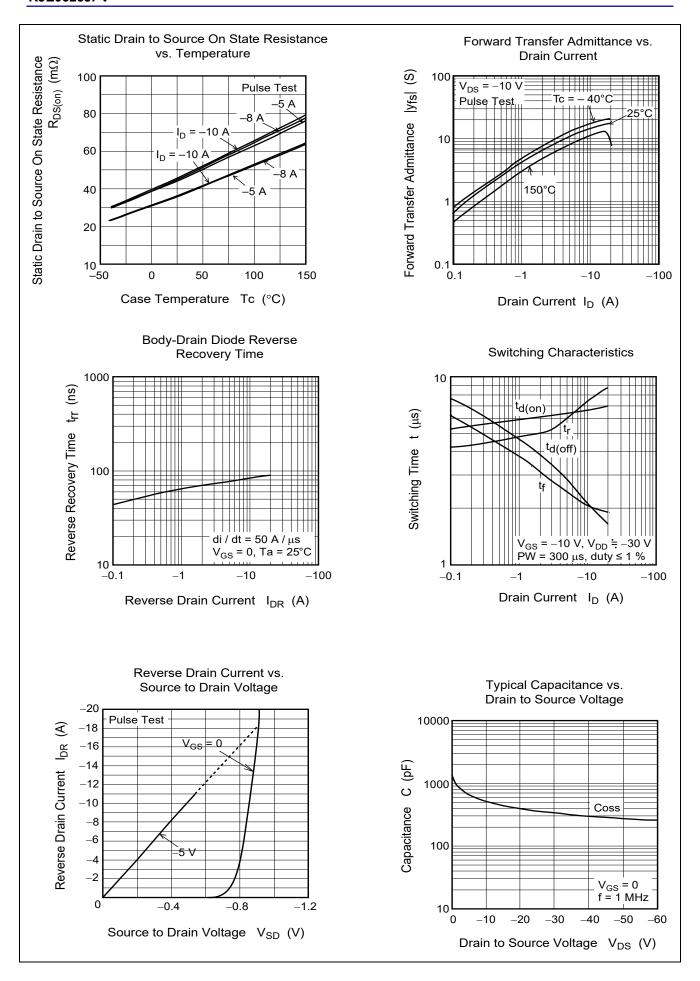
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I _{D1}	_	_	-12	Α	$V_{GS} = -3.5 \text{ V}, V_{DS} = -10 \text{ V}^{\text{Note 5}}$
	I _{D2}	_	_	-10	mA	V _{GS} = -1.2 V, V _{DS} = -10 V
	I _{D3}	-17	_	_	Α	V _{GS} = -12 V, V _{DS} = -10 V Note 5
Drain to source breakdown voltage	V _{(BR)DSS}	- 60	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown	V _{(BR)GSS}	-16	_	_	V	$I_G = -800 \mu A, V_{DS} = 0$
voltage	V _{(BR)GSS}	2.5	_	_	V	I _G = 100 μA, V _{DS} = 0
Gate to source leak current	I _{GSS1}	_	_	-100	μА	V _{GS} = -8 V, V _{DS} = 0
	I _{GSS2}	_	_	-50	μА	$V_{GS} = -3.5 \text{ V}, V_{DS} = 0$
	I _{GSS3}	_	_	-1	μА	V _{GS} = -1.2 V, V _{DS} = 0
	I _{GSS4}	_	_	100	μА	V _{GS} = 2.4 V, V _{DS} = 0
Input current (shut down)	I _{GS(OP)1}		-0.8	_	mA	V _{GS} = -8 V, V _{DS} = 0
	I _{GS(OP)2}		-0.35	_	mA	$V_{GS} = -3.5 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	-10	μА	V _{DS} = -60 V, V _{GS} = 0
Gate to source cutoff voltage	V _{GS(off)}	-2.2	_	-3.4	V	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$
Forward transfer admittance	y _{fs}	8.4	14.9	_	S	$I_D = -10 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note 5}}$
Static drain to source on state	R _{DS(on)}	_	46.6	61	mΩ	$I_D = -10 \text{ A}, V_{GS} = -6 \text{ V}^{\text{Note 5}}$
resistance	R _{DS(on)}		36.8	45	mΩ	I _D = -10 A, V _{GS} = -10 V Note 5
Output capacitance	Coss	_	515	_	pF	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{MHz}$
Turn-on delay time	t _{d(on)}	_	6.48	_	μS	$V_{GS} = -10 \text{ V}, I_{D} = -10 \text{ A}, R_{L} = 3 \Omega$
Rise time	t _r	_	7.09	_	μS	
Turn-off delay time	t _{d(off)}		2.06	_	μS]
Fall time	t _f	_	2.07	_	μS]
Body-drain diode forward	V_{DF}		-0.9	_	V	$I_F = -17 \text{ A}, V_{GS} = 0$
Body-drain diode reverse recovery time	t _{rr}	<u> </u>	91.1		ns	$I_F = -17 \text{ A}, V_{GS} = 0$ $di_F/dt = 50 \text{ A}/\mu\text{s}$
Over load shut down operation time Note 6	t _{os1}	_	1.7	_	ms	V _{GS} = -6 V, V _{DD} = -16 V

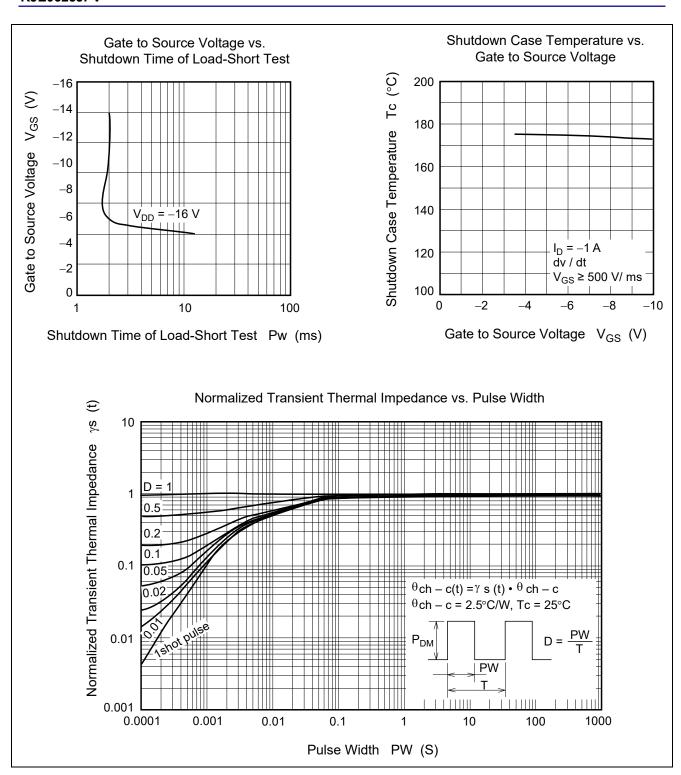
Notes: 5. Pulse test

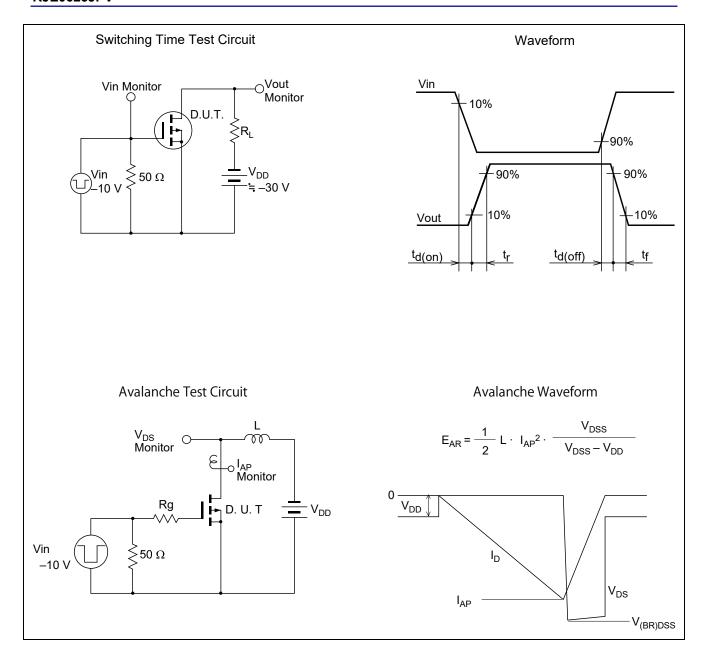
6. Including the junction temperature rise of the over loaded condition.

Main Characteristics

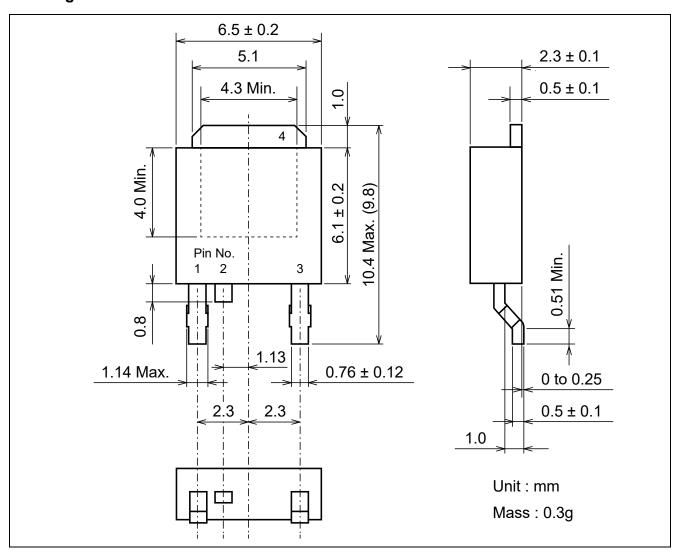








Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RJE0625JPV-00-Q7	2500 pcs	Taping (Sinistrorse)

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(Rev.5.0-1 October 2020)

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